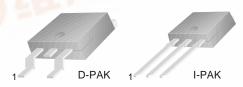


MJD44H11

General Purpose Power and Switching Such as Output or Driver Stages in Applications **D-PAK for Surface Mount Applications**

- Load Formed for Surface Mount Application (No Suffix)
- Straight Lead (I-PAK, "- I" Suffix)
- Electrically Similar to Popular MJE44H
- Fast Switching Speeds
- Low Collector Emitter Saturation Voltage



1.Base 2.Collector 3.Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	80	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	8	А
I _{CP}	Collector-Current (Pulse)	16	А
P _C	Collector Dissipation (T _C =25°C)	20	W
	Collector Dissipation (T _a =25°C)	1.75	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	V _{CEO} (sus)	*Collector-Emitter Sustaining Voltage	$I_C = 30 \text{mA}, I_B = 0$	80			V
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	I _{CEO}	Collector Cut-off Current	$V_{CE} = 80V, I_{B} = 0$			10	μΑ
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	I _{EBO}	Emitter Cut-off Current	$V_{BE} = 5V, I_{C} = 0$			50	μΑ
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	h _{FE}	*DC Current Gain	$V_{CE} = 1V$, $I_C = 2A$	60			
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			$V_{CE} = 1V$, $I_C = 4A$	40			
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	V _{CE} (sat)	*Collector-Emitter Saturation Voltage	$I_C = 8A, I_B = 0.4A$	7.11		1	V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	V _{BE} (on)	*Base-Emitter ON Voltage	$I_C = 8A, I_B = 0.8A$	112		1.5	V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.5A$		50	07.5	MHz
t_{STG} Storage Time $I_{B1} = -I_{B2} = 0.5A$ 500ns t_F Fall Time140ns	C _{ob}	Output Capacitance	V _{CB} =10V, f = 1MHz		130		pF
t _F Fall Time 140 ns	t _{ON}	Turn ON Time	I _C = 5A		300		ns
	t _{STG}	Storage Time	$I_{B1} = -I_{B2} = 0.5A$		500		ns
Pulse Test: PW≤300μs, Duty Cycle≤2%	t _F				140		ns
	Pulse Test: PW≤3	00μs, Duty Cycle≤2%	•				

Typical Characteristics

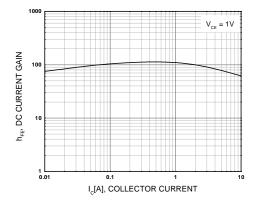


Figure 1. DC current Gain

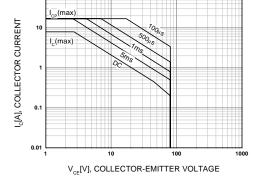


Figure 2. Safe Operating Area

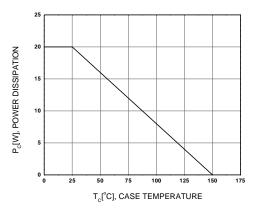
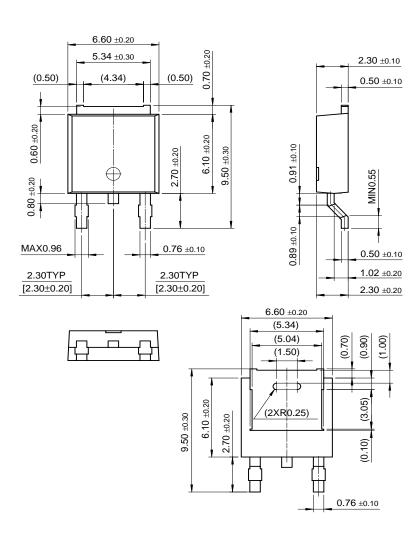


Figure 3. Power Derating

©2001 Fairchild Semiconductor Corporation Rev. A2, June 2001

Package Demensions

D-PAK



Dimensions in Millimeters

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™	FAST [®]	OPTOPLANAR™	STAR*POWER™
Bottomless™	FASTr™	PACMAN™	Stealth™
CoolFET™	FRFET™	POP^{TM}	SuperSOT™-3
$CROSSVOLT^{TM}$	GlobalOptoisolator™	Power247™	SuperSOT™-6
DenseTrench™	GTO™	PowerTrench [®]	SuperSOT™-8
DOME™	HiSeC™	QFET™	SyncFET™
EcoSPARK™	ISOPLANAR™	QS™	TruTranslation™
E ² CMOS™	LittleFET™	QT Optoelectronics™	TinyLogic™
EnSigna™	MicroFET™	Quiet Series™	UHC™
FACT™	MICROWIRE™	SLIENT SWITCHER®	UltraFET [®]
FACT Quiet Series™	OPTOLOGIC™	SMART START™	VCX™

STAR*POWER is used under license

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.